NSN 5962-01-310-7279

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View Online at https://aerobasegroup.com/nsn/5962-01-310-7279

Body Length: 0.840 inches Body Width: Between 0.220 inches and 0.310 inches Body Height: Between 0.140 inches and 0.185 inches Operating Tempurature Range: +0.0/+75.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius Features Provided: Hermetically sealed and burn in and bind

Hermetically sealed and burn in and bipolar and w/enable and programmable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Case Outline Source And Designator:

D-2 mil-m-38510

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

70.00 nanoseconds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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